

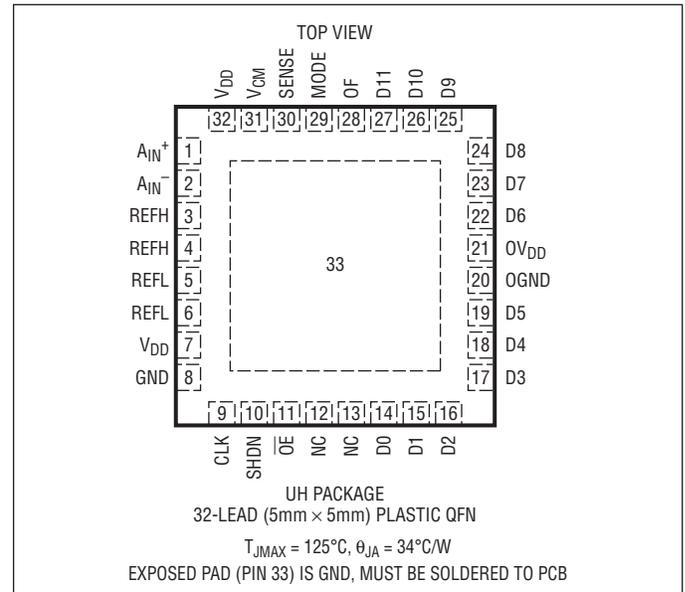
LTC2228/LTC2227/LTC2226

ABSOLUTE MAXIMUM RATINGS

$OV_{DD} = V_{DD}$ (Notes 1, 2)

Supply Voltage (V_{DD})	4V
Digital Output Ground Voltage (OGND)	-0.3V to 1V
Analog Input Voltage (Note 3)	-0.3V to ($V_{DD} + 0.3V$)
Digital Input Voltage	-0.3V to ($V_{DD} + 0.3V$)
Digital Output Voltage	-0.3V to ($OV_{DD} + 0.3V$)
Power Dissipation	1500mW
Operating Temperature Range	
LTC2228C, LTC2227C, LTC2226C	0°C to 70°C
LTC2228I, LTC2227I, LTC2226I	-40°C to 85°C
Storage Temperature Range	-65°C to 125°C

PIN CONFIGURATION



ORDER INFORMATION

LEAD FREE FINISH	TAPE AND REEL	PART MARKING*	PACKAGE DESCRIPTION	TEMPERATURE RANGE
LTC2228CUH#PBF	LTC2228CUH#TRPBF	2228	32-Lead (5mm × 5mm) Plastic QFN	0°C to 70°C
LTC2228IUH#PBF	LTC2228IUH#TRPBF	2228	32-Lead (5mm × 5mm) Plastic QFN	-40°C to 85°C
LTC2227CUH#PBF	LTC2227CUH#TRPBF	2227	32-Lead (5mm × 5mm) Plastic QFN	0°C to 70°C
LTC2227IUH#PBF	LTC2227IUH#TRPBF	2227	32-Lead (5mm × 5mm) Plastic QFN	-40°C to 85°C
LTC2226CUH#PBF	LTC2226CUH#TRPBF	2226	32-Lead (5mm × 5mm) Plastic QFN	0°C to 70°C
LTC2226IUH#PBF	LTC2226IUH#TRPBF	2226	32-Lead (5mm × 5mm) Plastic QFN	-40°C to 85°C
LEAD BASED FINISH	TAPE AND REEL	PART MARKING*	PACKAGE DESCRIPTION	TEMPERATURE RANGE
LTC2228CUH	LTC2228CUH#TR	2228	32-Lead (5mm × 5mm) Plastic QFN	0°C to 70°C
LTC2228IUH	LTC2228IUH#TR	2228	32-Lead (5mm × 5mm) Plastic QFN	-40°C to 85°C
LTC2227CUH	LTC2227CUH#TR	2227	32-Lead (5mm × 5mm) Plastic QFN	0°C to 70°C
LTC2227IUH	LTC2227IUH#TR	2227	32-Lead (5mm × 5mm) Plastic QFN	-40°C to 85°C
LTC2226CUH	LTC2226CUH#TR	2226	32-Lead (5mm × 5mm) Plastic QFN	0°C to 70°C
LTC2226IUH	LTC2226IUH#TR	2226	32-Lead (5mm × 5mm) Plastic QFN	-40°C to 85°C

Consult LTC Marketing for parts specified with wider operating temperature ranges. *The temperature grade is identified by a label on the shipping container.

For more information on lead free part marking, go to: <http://www.linear.com/leadfree/>

For more information on tape and reel specifications, go to: <http://www.linear.com/tapeandreeel/>

CONVERTER CHARACTERISTICS The ● denotes the specifications which apply over the full operating temperature range, otherwise specifications are at $T_A = 25^\circ\text{C}$. (Note 4)

PARAMETER	CONDITIONS		LTC2228			LTC2227			LTC2226			UNITS
			MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	
Resolution (No Missing Codes)		●	12			12			12			Bits
Integral Linearity Error	Differential Analog Input (Note 5)	●	-1.1	±0.3	1.1	-1	±0.3	1	-1	±0.3	1	LSB
Differential Linearity Error	Differential Analog Input	●	-0.8	±0.15	0.8	-0.7	±0.15	0.7	-0.7	±0.15	0.7	LSB
Offset Error	(Note 6)	●	-12	±2	12	-12	±2	12	-12	±2	12	mV
Gain Error	External Reference	●	-2.5	±0.5	2.5	-2.5	±0.5	2.5	-2.5	±0.5	2.5	%FS
Offset Drift				±10			±10			±10		$\mu\text{V}/^\circ\text{C}$
Full-Scale Drift	Internal Reference			±30			±30			±30		ppm/ $^\circ\text{C}$
	External Reference			±5			±5			±5		ppm/ $^\circ\text{C}$
Transition Noise	SENSE = 1V			0.25			0.25			0.25		LSB_{RMS}

ANALOG INPUT The ● denotes the specifications which apply over the full operating temperature range, otherwise specifications are at $T_A = 25^\circ\text{C}$. (Note 4)

SYMBOL	PARAMETER	CONDITIONS		MIN	TYP	MAX	UNITS
V_{IN}	Analog Input Range ($A_{\text{IN}}^+ - A_{\text{IN}}^-$)	$2.7\text{V} < V_{\text{DD}} < 3.4\text{V}$ (Note 7)	●	±0.5V to ±1V			V
$V_{\text{IN,CM}}$	Analog Input Common Mode ($A_{\text{IN}}^+ + A_{\text{IN}}^-$)/2	Differential Input (Note 7)	●	1	1.5	1.9	V
		Single-Ended Input (Note 7)	●	0.5	1.5	2	V
I_{IN}	Analog Input Leakage Current	$0\text{V} < A_{\text{IN}}^+, A_{\text{IN}}^- < V_{\text{DD}}$	●	-1		1	μA
I_{SENSE}	SENSE Input Leakage	$0\text{V} < \text{SENSE} < 1\text{V}$	●	-3		3	μA
I_{MODE}	MODE Pin Leakage		●	-3		3	μA
t_{AP}	Sample-and-Hold Acquisition Delay Time				0		ns
t_{JITTER}	Sample-and-Hold Acquisition Delay Time Jitter				0.2		pS_{RMS}
CMRR	Analog Input Common Mode Rejection Ratio				80		dB
	Full Power Bandwidth	Figure 8 Test Circuit			575		MHz

DYNAMIC ACCURACY The ● denotes the specifications which apply over the full operating temperature range, otherwise specifications are at $T_A = 25^\circ\text{C}$. $A_{\text{IN}} = -1\text{dBFS}$. (Note 4)

SYMBOL	PARAMETER	CONDITIONS		LTC2228			LTC2227			LTC2226			UNITS
				MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	
SNR	Signal-to-Noise Ratio	5MHz Input			71.3			71.4			71.4	dB	
		12.5MHz Input	●							70.2	71.2	dB	
		20MHz Input	●				70.1	71.3				dB	
		30MHz Input	●	70	71.3							dB	
		70MHz Input			71.3			71.1			70.9		dB
		140MHz Input			71			70.7			70.6		dB
SFDR	Spurious Free Dynamic Range 2nd or 3rd Harmonic	5MHz Input			90			90			90	dB	
		12.5MHz Input	●							76	90	dB	
		20MHz Input	●				76	90				dB	
		30MHz Input	●	75	90							dB	
		70MHz Input			85			85			85	dB	
		140MHz Input			80			80			80	dB	

LTC2228/LTC2227/LTC2226

DYNAMIC ACCURACY The ● denotes the specifications which apply over the full operating temperature range, otherwise specifications are at $T_A = 25^\circ\text{C}$. $A_{IN} = -1\text{dBFS}$. (Note 4)

SYMBOL	PARAMETER	CONDITIONS	LTC2228			LTC2227			LTC2226			UNITS	
			MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX		
SFDR	Spurious Free Dynamic Range 4th Harmonic or Higher	5MHz Input		95			95			95		dB	
		12.5MHz Input	●						82	95		dB	
		20MHz Input	●			82	95					dB	
		30MHz Input	●	82	95							dB	
		70MHz Input			95			95			95		dB
		140MHz Input			90			90			90		dB
S/(N+D)	Signal-to-Noise Plus Distortion Ratio	5MHz Input		71.3			71.4			71.4		dB	
		12.5MHz Input	●						69.8	71.2		dB	
		20MHz Input	●			69.7	71.2					dB	
		30MHz Input	●	69.6	71.2							dB	
		70MHz Input			71.1			70.9			70.8		dB
		140MHz Input			69.9			69.9			69.8		dB
IMD	Intermodulation Distortion	$f_{IN1} = 28.2\text{MHz}$, $f_{IN2} = 26.8\text{MHz}$		90			90			90		dB	

INTERNAL REFERENCE CHARACTERISTICS (Note 4)

PARAMETER	CONDITIONS	MIN	TYP	MAX	UNITS
V_{CM} Output Voltage	$I_{OUT} = 0$	1.475	1.500	1.525	V
V_{CM} Output Tempco			± 25		ppm/ $^\circ\text{C}$
V_{CM} Line Regulation	$2.7\text{V} < V_{DD} < 3.4\text{V}$		3		mV/V
V_{CM} Output Resistance	$-1\text{mA} < I_{OUT} < 1\text{mA}$		4		Ω

DIGITAL INPUTS AND DIGITAL OUTPUTS The ● denotes the specifications which apply over the full operating temperature range, otherwise specifications are at $T_A = 25^\circ\text{C}$. (Note 4)

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNITS
LOGIC INPUTS (CLK, $\overline{\text{OE}}$, SHDN)						
V_{IH}	High Level Input Voltage	$V_{DD} = 3\text{V}$	●	2		V
V_{IL}	Low Level Input Voltage	$V_{DD} = 3\text{V}$	●		0.8	V
I_{IN}	Input Current	$V_{IN} = 0\text{V}$ to V_{DD}	●	-10	10	μA
C_{IN}	Input Capacitance	(Note 7)		3		pF
LOGIC OUTPUTS						
$0V_{DD} = 3\text{V}$						
C_{OZ}	Hi-Z Output Capacitance	$\overline{\text{OE}} = \text{High}$ (Note 7)		3		pF
I_{SOURCE}	Output Source Current	$V_{OUT} = 0\text{V}$		50		mA
I_{SINK}	Output Sink Current	$V_{OUT} = 3\text{V}$		50		mA
V_{OH}	High Level Output Voltage	$I_O = -10\mu\text{A}$ $I_O = -200\mu\text{A}$	●	2.7	2.995	V
					2.99	V
V_{OL}	Low Level Output Voltage	$I_O = 10\mu\text{A}$ $I_O = 1.6\text{mA}$	●		0.005	V
					0.09	0.4
$0V_{DD} = 2.5\text{V}$						
V_{OH}	High Level Output Voltage	$I_O = -200\mu\text{A}$		2.49		V
V_{OL}	Low Level Output Voltage	$I_O = 1.6\text{mA}$		0.09		V
$0V_{DD} = 1.8\text{V}$						
V_{OH}	High Level Output Voltage	$I_O = -200\mu\text{A}$		1.79		V
V_{OL}	Low Level Output Voltage	$I_O = 1.6\text{mA}$		0.09		V

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POWER REQUIREMENTS

The ● denotes the specifications which apply over the full operating temperature range, otherwise specifications are at $T_A = 25^\circ\text{C}$. (Note 8)

SYMBOL	PARAMETER	CONDITIONS	LTC2228			LTC2227			LTC2226			UNITS
			MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	
V_{DD}	Analog Supply Voltage	(Note 9)	● 2.7	3	3.4	2.7	3	3.4	2.7	3	3.4	V
OV_{DD}	Output Supply Voltage	(Note 9)	● 0.5	3	3.6	0.5	3	3.6	0.5	3	3.6	V
I_{VDD}	Supply Current		●	68.3	80		40	48		25	30	mA
P_{DISS}	Power Dissipation		●	205	240		120	144		75	90	mW
P_{SHDN}	Shutdown Power	SHDN = H, \overline{OE} = H, No CLK		2			2			2		mW
P_{NAP}	Nap Mode Power	SHDN = H, \overline{OE} = L, No CLK		15			15			15		mW

TIMING CHARACTERISTICS

The ● denotes the specifications which apply over the full operating temperature range, otherwise specifications are at $T_A = 25^\circ\text{C}$. (Note 4)

SYMBOL	PARAMETER	CONDITIONS	LTC2228			LTC2227			LTC2226			UNITS
			MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	
f_S	Sampling Frequency	(Note 9)	● 1		65	1		40	1		25	MHz
t_L	CLK Low Time	Duty Cycle Stabilizer Off	● 7.3	7.7	500	11.8	12.5	500	18.9	20	500	ns
		Duty Cycle Stabilizer On (Note 7)	● 5	7.7	500	5		500	5	20	500	ns
t_H	CLK High Time	Duty Cycle Stabilizer Off	● 7.3	7.7	500	11.8	12.5	500	18.9	20	500	ns
		Duty Cycle Stabilizer On (Note 7)	● 5	7.7	500	5	12.5	500	5	20	500	ns
t_{AP}	Sample-and-Hold Aperture Delay			0			0			0		ns
t_D	CLK to DATA Delay	$C_L = 5\text{pF}$ (Note 7)	● 1.4	2.7	5.4	1.4	2.7	5.4	1.4	2.7	5.4	ns
	Data Access Time After \overline{OE} ↓	$C_L = 5\text{pF}$ (Note 7)	●	4.3	10		4.3	10		4.3	10	ns
	BUS Relinquish Time	(Note 7)	●	3.3	8.5		3.3	8.5		3.3	8.5	ns
Pipeline Latency				5			5			5		Cycles

Note 1: Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. Exposure to any Absolute Maximum Rating condition for extended periods may affect device reliability and lifetime.

Note 2: All voltage values are with respect to ground with GND and OGND wired together (unless otherwise noted).

Note 3: When these pin voltages are taken below GND or above V_{DD} , they will be clamped by internal diodes. This product can handle input currents of greater than 100mA below GND or above V_{DD} without latchup.

Note 4: $V_{DD} = 3\text{V}$, $f_{\text{SAMPLE}} = 65\text{MHz}$ (LTC2228), 40MHz (LTC2227), or 25MHz (LTC2226), input range = $2V_{P-P}$ with differential drive, unless otherwise noted.

Note 5: Integral nonlinearity is defined as the deviation of a code from a straight line passing through the actual endpoints of the transfer curve. The deviation is measured from the center of the quantization band.

Note 6: Offset error is the offset voltage measured from -0.5 LSB when the output code flickers between 0000 0000 0000 and 1111 1111 1111.

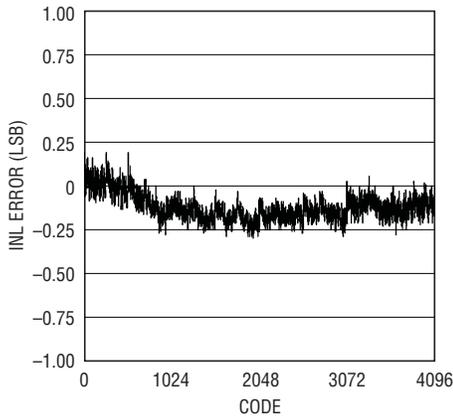
Note 7: Guaranteed by design, not subject to test.

Note 8: $V_{DD} = 3\text{V}$, $f_{\text{SAMPLE}} = 65\text{MHz}$ (LTC2228), 40MHz (LTC2227), or 25MHz (LTC2226), input range = $1V_{P-P}$ with differential drive.

Note 9: Recommend operating conditions.

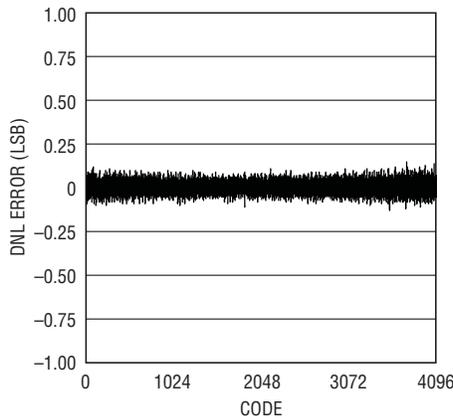
TYPICAL PERFORMANCE CHARACTERISTICS

LTC2228: Typical INL, 2V Range, 65Mps



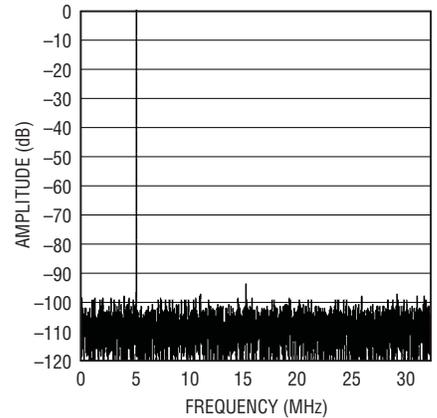
2228 G01

LTC2228: Typical DNL, 2V Range, 65Mps



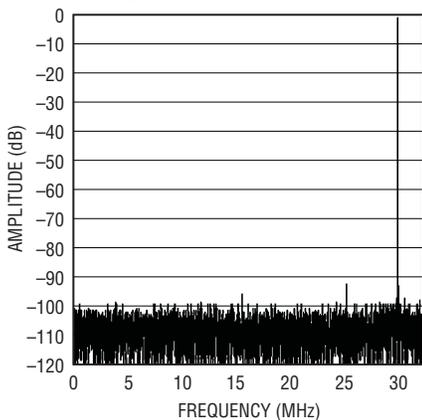
2228 G02

LTC2228: 8192 Point FFT, $f_{IN} = 5\text{MHz}$, -1dB, 2V Range, 65Mps



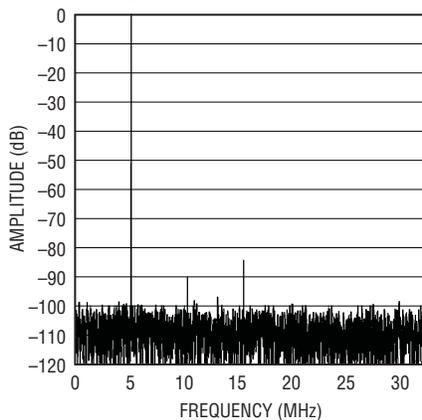
2228 G03

LTC2228: 8192 Point FFT, $f_{IN} = 30\text{MHz}$, -1dB, 2V Range, 65Mps



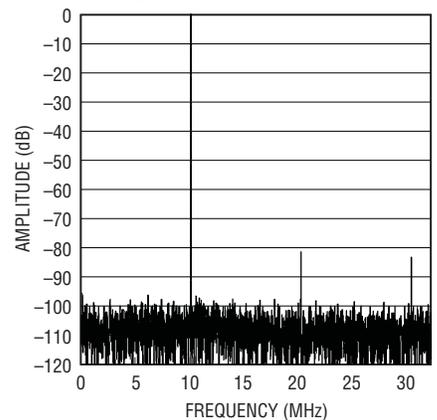
2228 G04

LTC2228: 8192 Point FFT, $f_{IN} = 70\text{MHz}$, -1dB, 2V Range, 65Mps



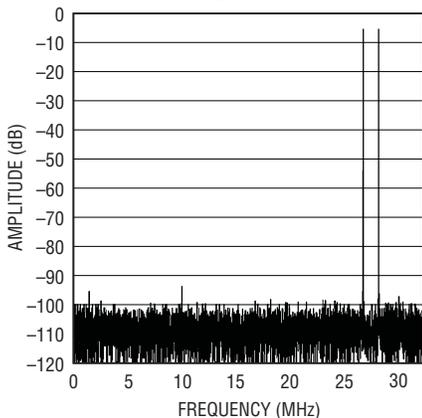
2228 G05

LTC2228: 8192 Point FFT, $f_{IN} = 140\text{MHz}$, -1dB, 2V Range, 65Mps



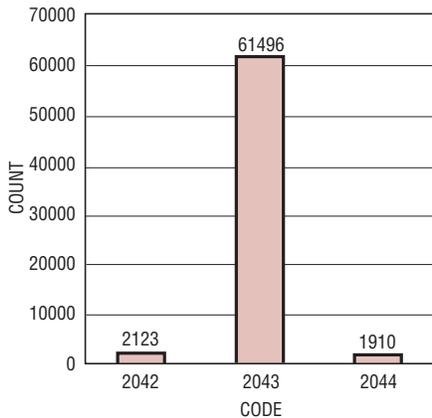
2228 G06

LTC2228: 8192 Point 2-Tone FFT, $f_{IN} = 28.2\text{MHz}$ and 26.8MHz , -1dB, 2V Range, 65Mps



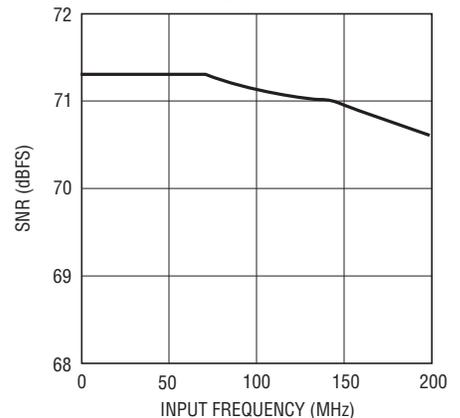
2228 G07

LTC2228: Grounded Input Histogram, 65Mps



2228 G08

LTC2228: SNR vs Input Frequency, -1dB, 2V Range, 65Mps

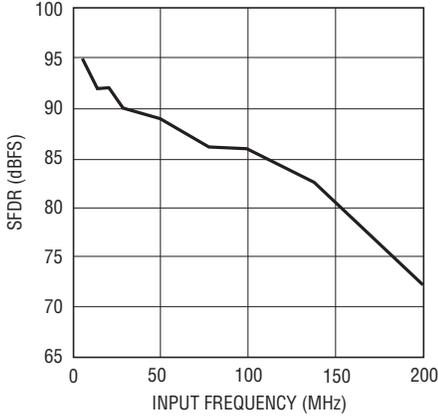


2228 G09

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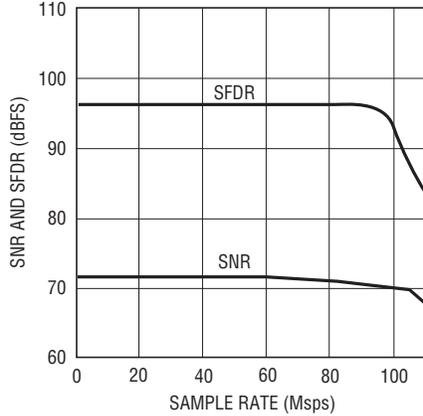
TYPICAL PERFORMANCE CHARACTERISTICS

LTC2228: SFDR vs Input Frequency, -1dB, 2V Range, 65Mps



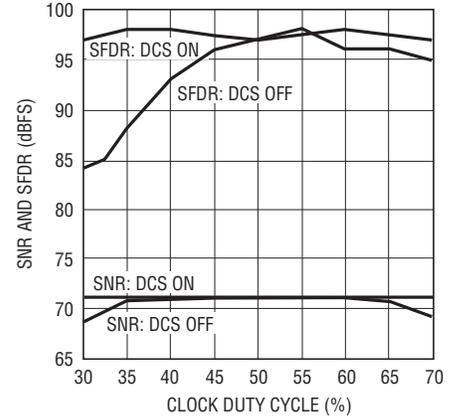
2228 G10

LTC2228: SNR and SFDR vs Sample Rate, 2V Range, $f_{IN} = 5\text{MHz}$, -1dB



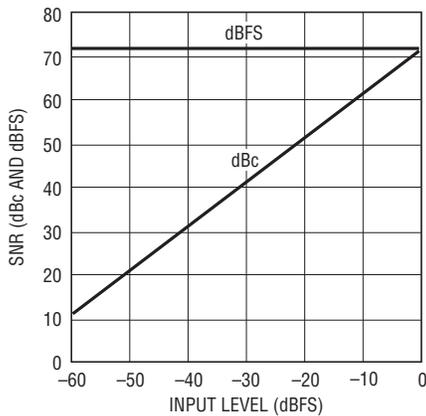
2228 G11

LTC2228: SNR and SFDR vs Clock Duty Cycle, 65Mps



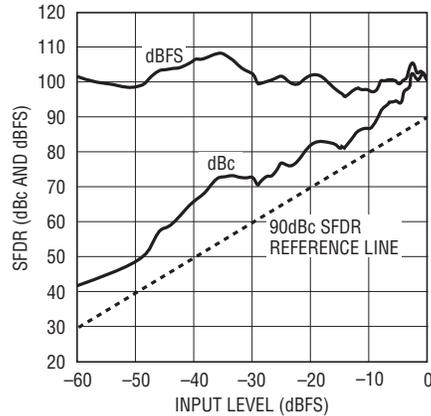
2228 G12

LTC2228: SNR vs Input Level, $f_{IN} = 30\text{MHz}$, 2V Range, 65Mps



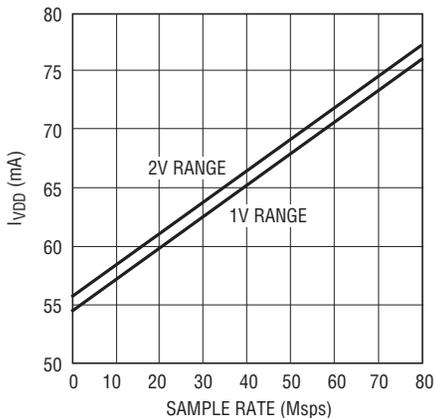
2228 G13

LTC2228: SFDR vs Input Level, $f_{IN} = 30\text{MHz}$, 2V Range, 65Mps



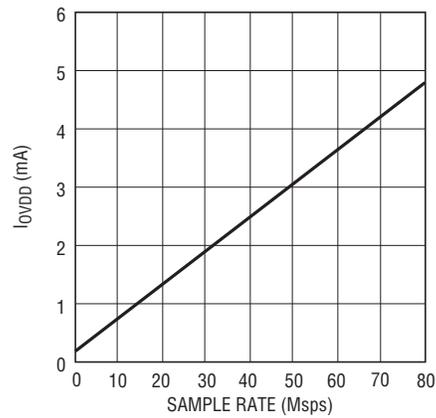
2228 G14

LTC2228: I_{VDD} vs Sample Rate, 5MHz Sine Wave Input, -1dB



2228 G15

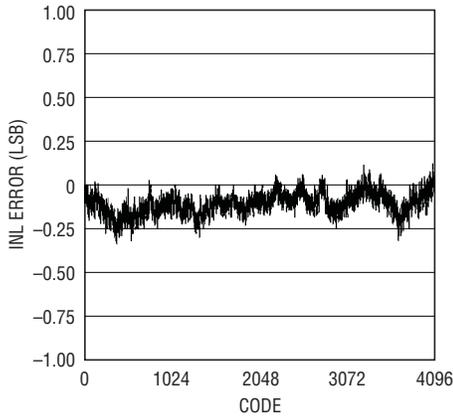
LTC2228: I_{OVD} vs Sample Rate, 5MHz Sine Wave Input, -1dB, $O_{VDD} = 1.8\text{V}$



2228 G16

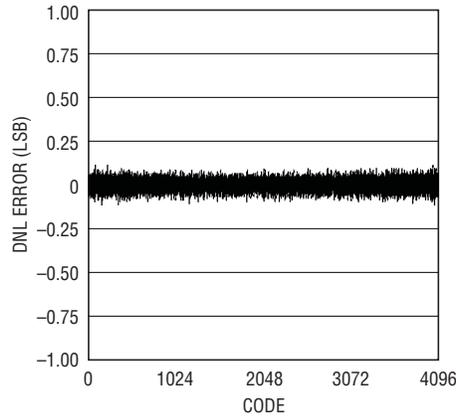
TYPICAL PERFORMANCE CHARACTERISTICS

LTC2227: Typical INL, 2V Range, 40Msps



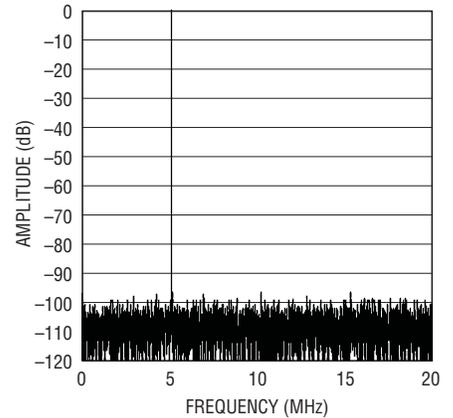
2227 G01

LTC2227: Typical DNL, 2V Range, 40Msps



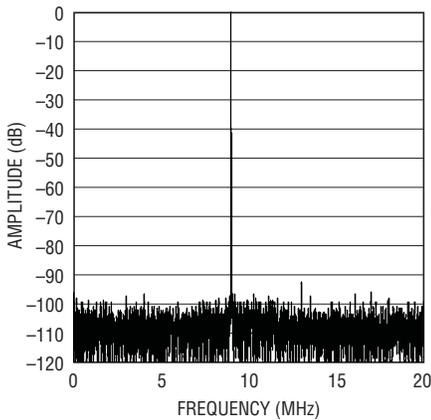
2227 G02

LTC2227: 8192 Point FFT, $f_{IN} = 5\text{MHz}$, -1dB, 2V Range, 40Msps



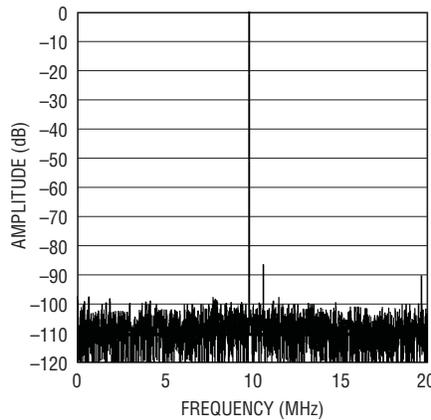
2227 G03

LTC2228: 8192 Point FFT, $f_{IN} = 30\text{MHz}$, -1dB, 2V Range, 40Msps



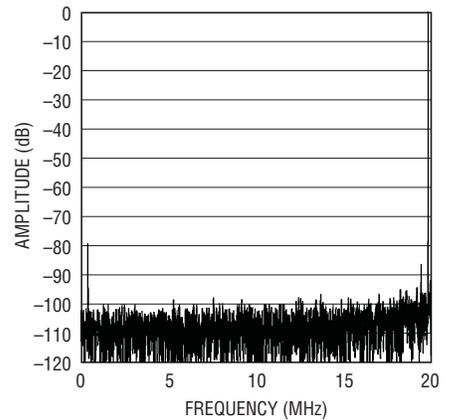
2227 G04

LTC2227: 8192 Point FFT, $f_{IN} = 70\text{MHz}$, -1dB, 2V Range, 40Msps



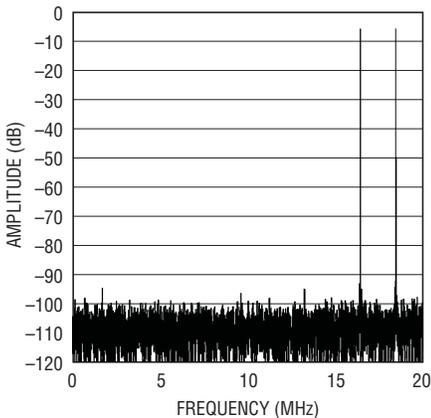
2227 G05

LTC2227: 8192 Point FFT, $f_{IN} = 140\text{MHz}$, -1dB, 2V Range, 40Msps



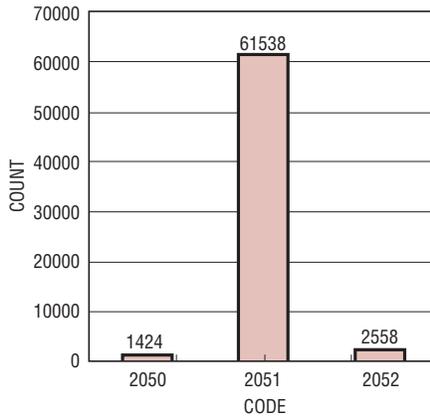
2227 G06

LTC2227: 8192 Point 2-Tone FFT, $f_{IN} = 21.6\text{MHz}$ and 23.6MHz , -1dB, 2V Range, 40Msps



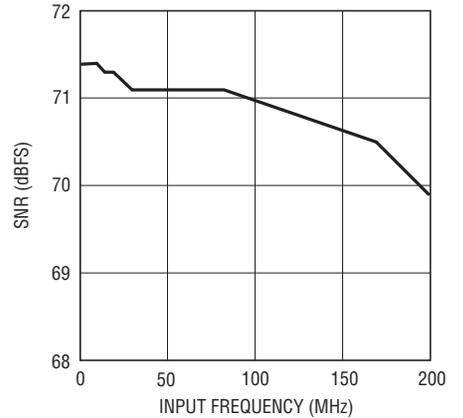
2227 G07

LTC2227: Grounded Input Histogram, 40Msps



2227 G08

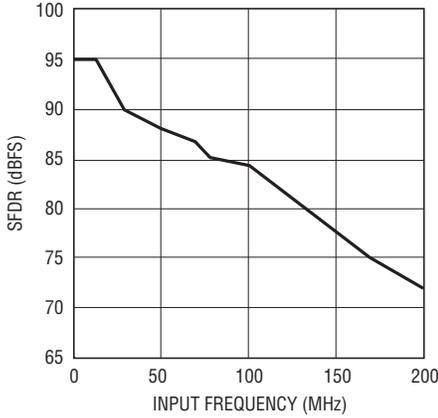
LTC2227: SNR vs Input Frequency, -1dB, 2V Range, 40Msps



2227 G09
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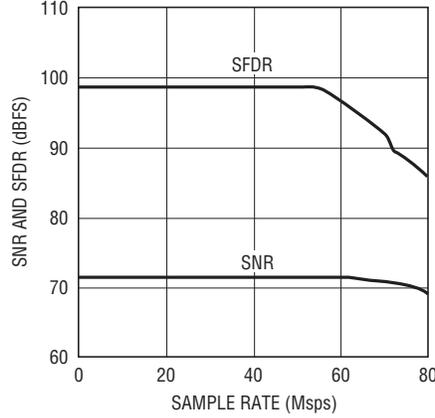
TYPICAL PERFORMANCE CHARACTERISTICS

LTC2227: SFDR vs Input Frequency, -1dB, 2V Range, 40Mps



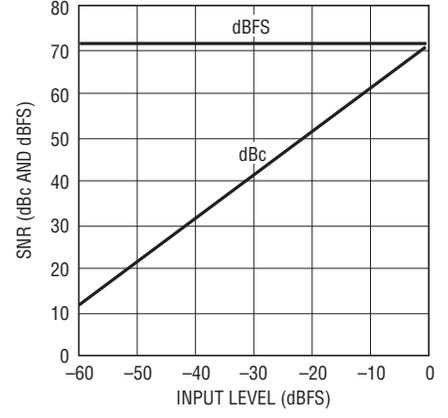
2227 G10

LTC2227: SNR and SFDR vs Sample Rate, 2V Range, $f_{IN} = 5\text{MHz}$, -1dB



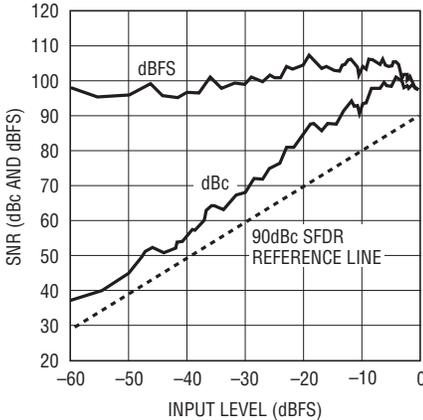
2227 G11

LTC2227: SNR vs Input Level, $f_{IN} = 5\text{MHz}$, 2V Range, 40Mps



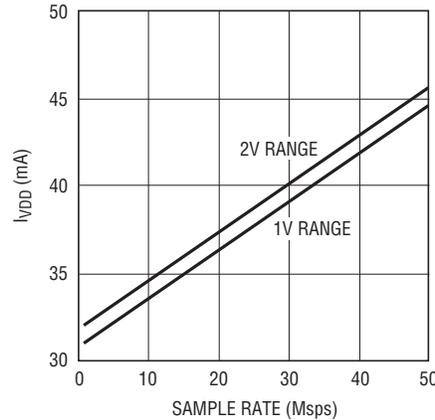
2227 G12

LTC2227: SFDR vs Input Level, $f_{IN} = 5\text{MHz}$, 2V Range, 40Mps



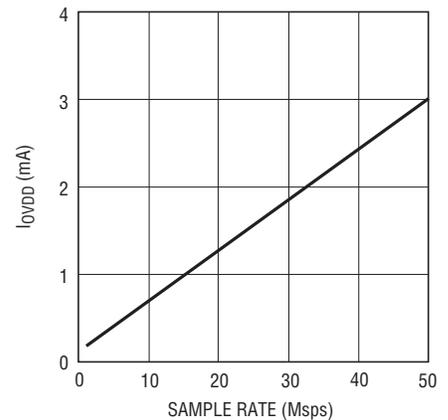
2227 G13

LTC2227: I_{VDD} vs Sample Rate, 5MHz Sine Wave Input, -1dB



2227 G14

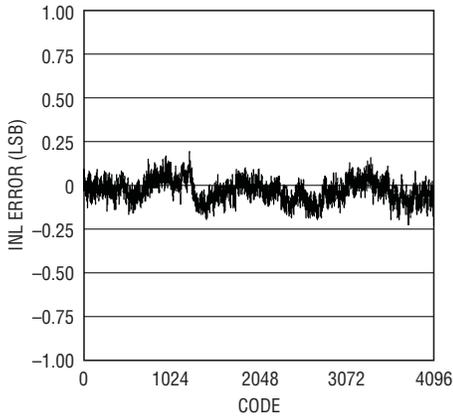
LTC2227: I_{OVD} vs Sample Rate, 5MHz Sine Wave Input, -1dB, $O_{VDD} = 1.8\text{V}$



2227 G15

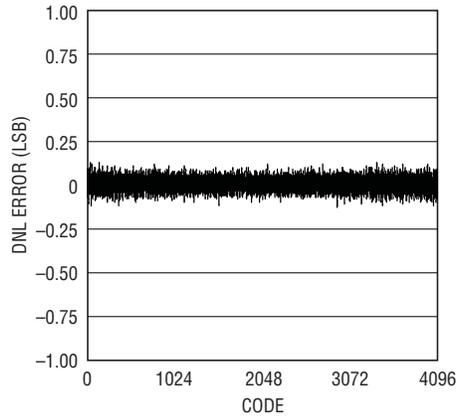
TYPICAL PERFORMANCE CHARACTERISTICS

LTC2226: Typical INL, 2V Range, 25Msps



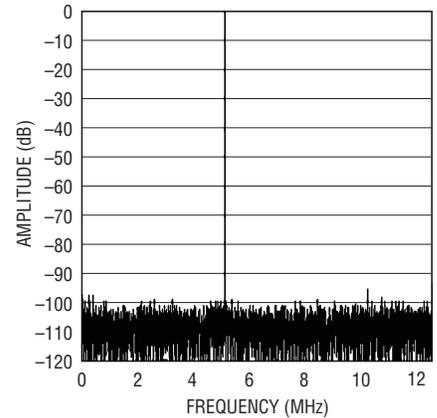
2226 G01

LTC2226: Typical DNL, 2V Range, 25Msps



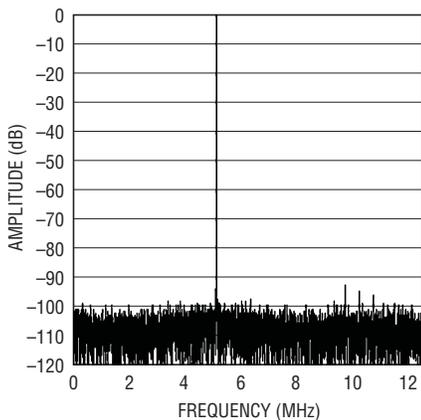
2226 G02

LTC2226: 8192 Point FFT, $f_{IN} = 5\text{MHz}$, -1dB, 2V Range, 25Msps



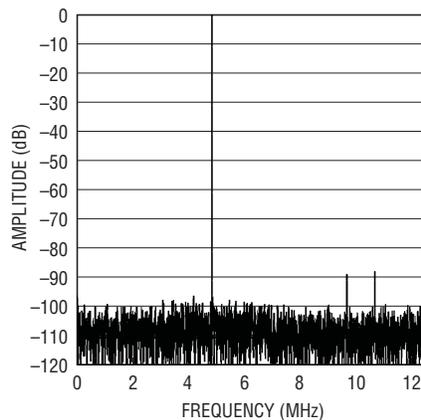
2226 G03

LTC2226: 8192 Point FFT, $f_{IN} = 30\text{MHz}$, -1dB, 2V Range, 25Msps



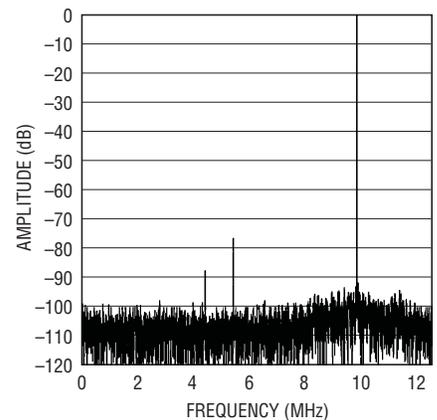
2226 G04

LTC2226: 8192 Point FFT, $f_{IN} = 70\text{MHz}$, -1dB, 2V Range, 25Msps



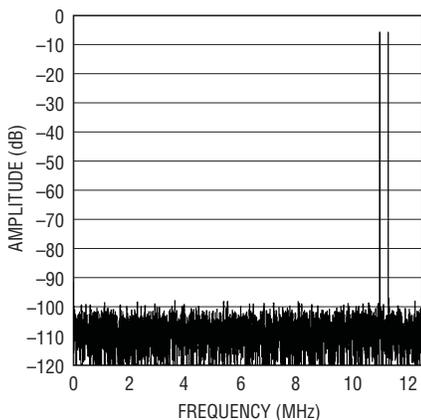
2226 G05

LTC2226: 8192 Point FFT, $f_{IN} = 140\text{MHz}$, -1dB, 2V Range, 25Msps



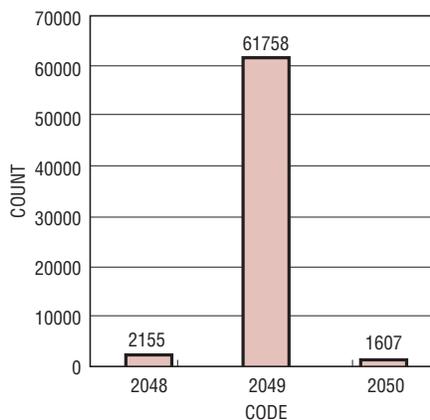
2226 G06

LTC2226: 8192 Point 2-Tone FFT, $f_{IN} = 10.9\text{MHz}$ and 13.8MHz , -1dB, 2V Range, 25Msps



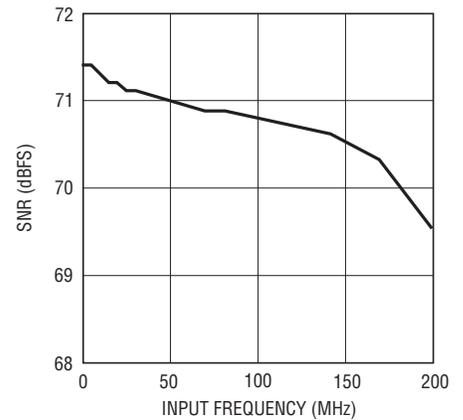
2226 G07

LTC2226: Grounded Input Histogram, 25Msps



2226 G08

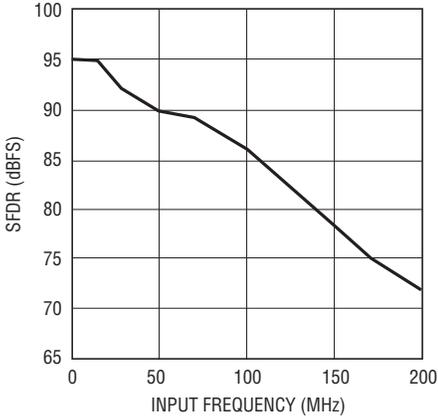
LTC2226: SNR vs Input Frequency, -1dB, 2V Range, 25Msps



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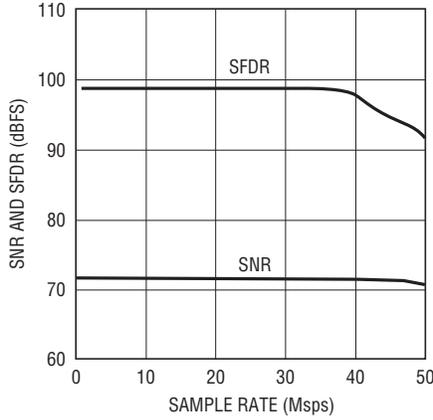
TYPICAL PERFORMANCE CHARACTERISTICS

LTC2226: SFDR vs Input Frequency, -1dB, 2V Range, 25Mps



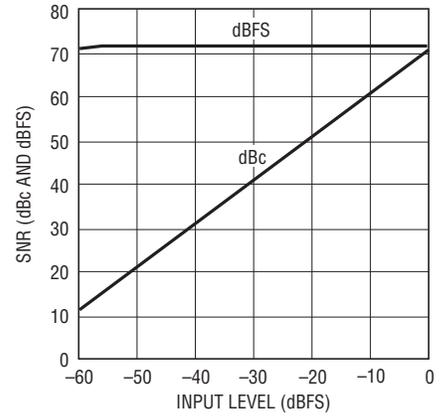
2226 G10

LTC2226: SNR and SFDR vs Sample Rate, 2V Range, $f_{IN} = 5\text{MHz}$, -1dB



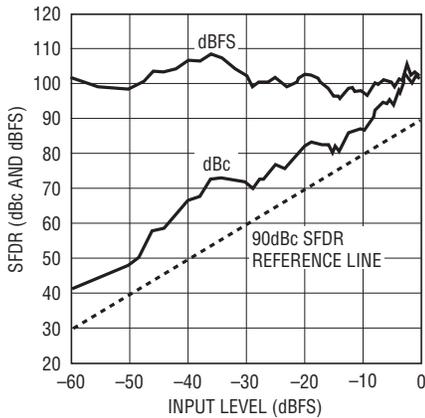
2226 G11

LTC2226: SNR vs Input Level, $f_{IN} = 5\text{MHz}$, 2V Range, 25Mps



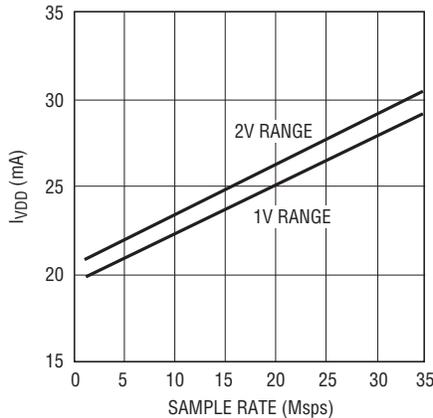
2227 G12

LTC2226: SFDR vs Input Level, $f_{IN} = 5\text{MHz}$, 2V Range, 25Mps



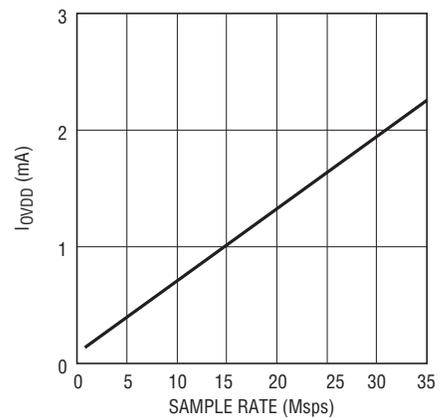
2226 G13

LTC2226: I_{VDD} vs Sample Rate, 5MHz Sine Wave Input, -1dB



2226 G14

LTC2226: I_{OVD} vs Sample Rate, 5MHz Sine Wave Input, -1dB, $O_{VDD} = 1.8\text{V}$



2226 G15

PIN FUNCTIONS

A_{IN}⁺ (Pin 1): Positive Differential Analog Input.

A_{IN}⁻ (Pin 2): Negative Differential Analog Input.

REFH (Pins 3, 4): ADC High Reference. Short together and bypass to Pins 5, 6 with a 0.1 μ F ceramic chip capacitor as close to the pin as possible. Also bypass to Pins 5, 6 with an additional 2.2 μ F ceramic chip capacitor and to ground with a 1 μ F ceramic chip capacitor.

REFL (Pins 5, 6): ADC Low Reference. Short together and bypass to Pins 3, 4 with a 0.1 μ F ceramic chip capacitor as close to the pin as possible. Also bypass to Pins 3, 4 with an additional 2.2 μ F ceramic chip capacitor and to ground with a 1 μ F ceramic chip capacitor.

V_{DD} (Pins 7, 32): 3V Supply. Bypass to GND with 0.1 μ F ceramic chip capacitors.

GND (Pin 8): ADC Power Ground.

CLK (Pin 9): Clock Input. The input sample starts on the positive edge.

SHDN (Pin 10): Shutdown Mode Selection Pin. Connecting SHDN to GND and \overline{OE} to GND results in normal operation with the outputs enabled. Connecting SHDN to GND and \overline{OE} to V_{DD} results in normal operation with the outputs at high impedance. Connecting SHDN to V_{DD} and \overline{OE} to GND results in nap mode with the outputs at high impedance. Connecting SHDN to V_{DD} and \overline{OE} to V_{DD} results in sleep mode with the outputs at high impedance.

\overline{OE} (Pin 11): Output Enable Pin. Refer to SHDN pin function.

NC (Pins 12, 13): Do Not Connect These Pins.

D0-D11 (Pins 14, 15, 16, 17, 18, 19, 22, 23, 24, 25, 26, 27): Digital Outputs. D11 is the MSB.

OGND (Pin 20): Output Driver Ground.

OV_{DD} (Pin 21): Positive Supply for the Output Drivers. Bypass to ground with 0.1 μ F ceramic chip capacitor.

OF (Pin 28): Over/Under Flow Output. High when an over or under flow has occurred.

MODE (Pin 29): Output Format and Clock Duty Cycle Stabilizer Selection Pin. Connecting MODE to GND selects offset binary output format and turns the clock duty cycle stabilizer off. 1/3 V_{DD} selects offset binary output format and turns the clock duty cycle stabilizer on. 2/3 V_{DD} selects 2's complement output format and turns the clock duty cycle stabilizer on. V_{DD} selects 2's complement output format and turns the clock duty cycle stabilizer off.

SENSE (Pin 30): Reference Programming Pin. Connecting SENSE to V_{CM} selects the internal reference and a $\pm 0.5V$ input range. V_{DD} selects the internal reference and a $\pm 1V$ input range. An external reference greater than 0.5V and less than 1V applied to SENSE selects an input range of $\pm V_{SENSE}$. $\pm 1V$ is the largest valid input range.

V_{CM} (Pin 31): 1.5V Output and Input Common Mode Bias. Bypass to ground with 2.2 μ F ceramic chip capacitor.

Exposed Pad (Pin 33): ADC Power Ground. The Exposed Pad on the bottom of the package needs to be soldered to ground.

FUNCTIONAL BLOCK DIAGRAM

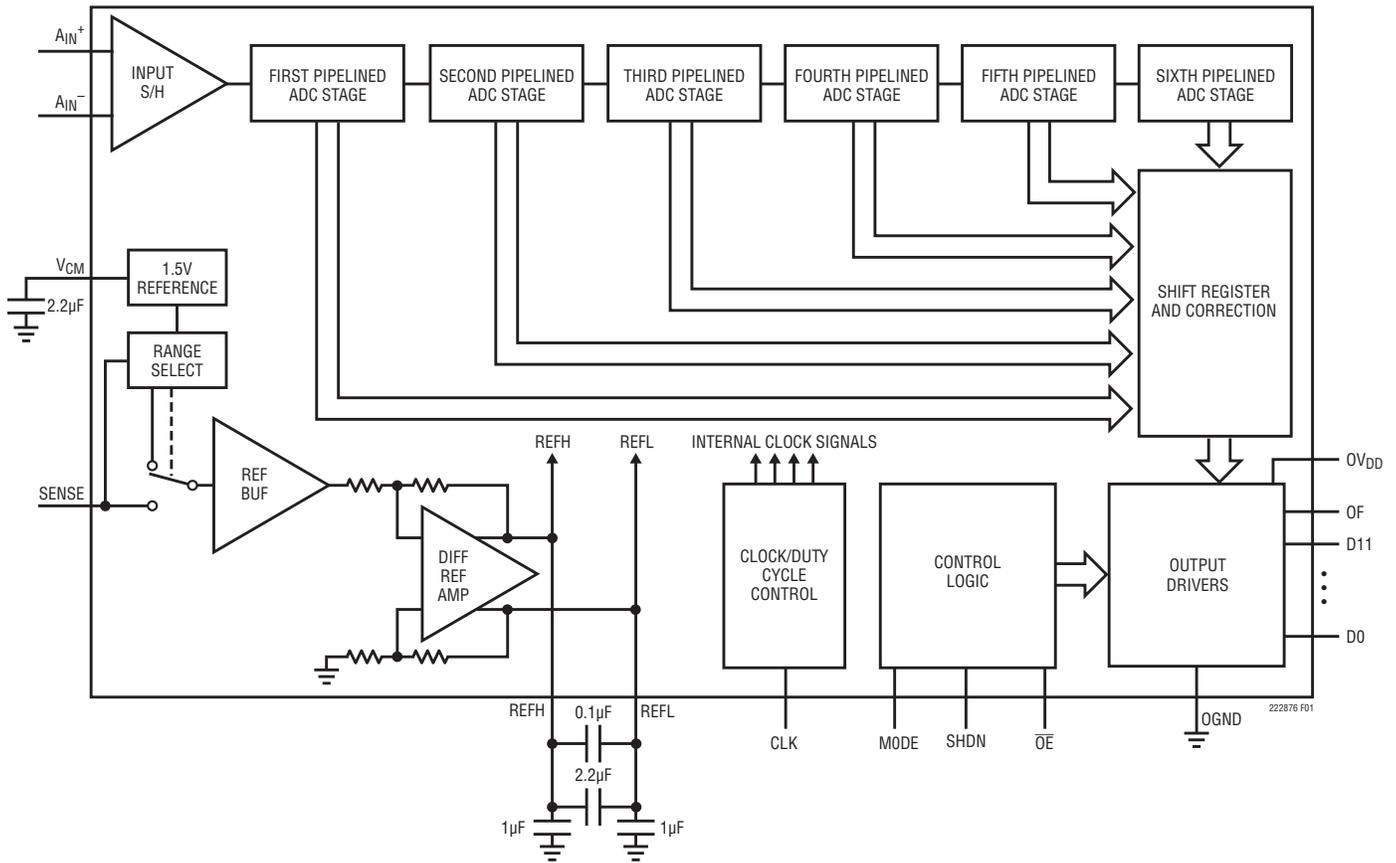
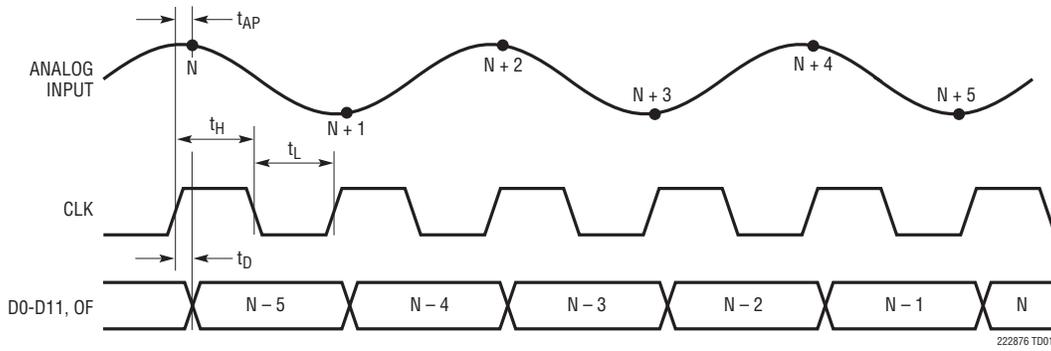


Figure 1. Functional Block Diagram

TIMING DIAGRAM

Timing Diagram



APPLICATIONS INFORMATION

DYNAMIC PERFORMANCE

Signal-to-Noise Plus Distortion Ratio

The signal-to-noise plus distortion ratio [S/(N + D)] is the ratio between the RMS amplitude of the fundamental input frequency and the RMS amplitude of all other frequency components at the ADC output. The output is band limited to frequencies above DC to below half the sampling frequency.

Signal-to-Noise Ratio

The signal-to-noise ratio (SNR) is the ratio between the RMS amplitude of the fundamental input frequency and the RMS amplitude of all other frequency components except the first five harmonics and DC.

Total Harmonic Distortion

Total harmonic distortion is the ratio of the RMS sum of all harmonics of the input signal to the fundamental itself. The out-of-band harmonics alias into the frequency band between DC and half the sampling frequency. THD is expressed as:

$$\text{THD} = 20\text{Log}(\sqrt{V_2^2 + V_3^2 + V_4^2 + \dots + V_n^2}/V_1)$$

where V_1 is the RMS amplitude of the fundamental frequency and V_2 through V_n are the amplitudes of the second through n th harmonics. The THD calculated in this data sheet uses all the harmonics up to the fifth.

Intermodulation Distortion

If the ADC input signal consists of more than one spectral component, the ADC transfer function nonlinearity can produce intermodulation distortion (IMD) in addition to THD. IMD is the change in one sinusoidal input caused by the presence of another sinusoidal input at a different frequency.

If two pure sine waves of frequencies f_a and f_b are applied to the ADC input, nonlinearities in the ADC transfer function can create distortion products at the sum and difference frequencies of $m f_a \pm n f_b$, where m and $n = 0, 1, 2, 3$, etc. The 3rd order intermodulation products are $2f_a + f_b$, $2f_b + f_a$, $2f_a - f_b$ and $2f_b - f_a$. The intermodulation distortion is defined as the ratio of the RMS value of either input tone to the RMS value of the largest 3rd order intermodulation product.

Spurious Free Dynamic Range (SFDR)

Spurious free dynamic range is the peak harmonic or spurious noise that is the largest spectral component excluding the input signal and DC. This value is expressed in decibels relative to the RMS value of a full-scale input signal.

Input Bandwidth

The input bandwidth is that input frequency at which the amplitude of the reconstructed fundamental is reduced by 3dB for a full-scale input signal.

Aperture Delay Time

The time from when CLK reaches mid-supply to the instant that the input signal is held by the sample-and-hold circuit.

Aperture Delay Jitter

The variation in the aperture delay time from conversion to conversion. This random variation will result in noise when sampling an AC input. The signal to noise ratio due to the jitter alone will be:

$$\text{SNR}_{\text{JITTER}} = -20\text{log}(2\pi \cdot f_{\text{IN}} \cdot t_{\text{JITTER}})$$

APPLICATIONS INFORMATION

CONVERTER OPERATION

As shown in Figure 1, the LTC2228/LTC2227/LTC2226 is a CMOS pipelined multi-step converter. The converter has six pipelined ADC stages; a sampled analog input will result in a digitized value five cycles later (see the Timing Diagram section). For optimal AC performance the analog inputs should be driven differentially. For cost sensitive applications, the analog inputs can be driven single-ended with slightly worse harmonic distortion. The CLK input is single-ended. The LTC2228/LTC2227/LTC2226 has two phases of operation, determined by the state of the CLK input pin.

Each pipelined stage shown in Figure 1 contains an ADC, a reconstruction DAC and an interstage residue amplifier. In operation, the ADC quantizes the input to the stage and the quantized value is subtracted from the input by the DAC to produce a residue. The residue is amplified and output by the residue amplifier. Successive stages operate out of phase so that when the odd stages are outputting their residue, the even stages are acquiring that residue and vice versa.

When CLK is low, the analog input is sampled differentially directly onto the input sample-and-hold capacitors, inside the "Input S/H" shown in the Block Diagram. At the instant that CLK transitions from low to high, the sampled input is held. While CLK is high, the held input voltage is buffered by the S/H amplifier which drives the first pipelined ADC stage. The first stage acquires the output of the S/H during this high phase of CLK. When CLK goes back low, the first stage produces its residue which is acquired by the second stage. At the same time, the input S/H goes back to acquiring the analog input. When CLK goes back high, the second stage produces its residue which is acquired by the third stage. An identical process is repeated for the third, fourth and fifth stages, resulting in a fifth stage residue that is sent to the sixth stage ADC for final evaluation.

Each ADC stage following the first has additional range to accommodate flash and amplifier offset errors. Results from all of the ADC stages are digitally synchronized such that the results can be properly combined in the correction logic before being sent to the output buffer.

SAMPLE/HOLD OPERATION AND INPUT DRIVE

Sample/Hold Operation

Figure 2 shows an equivalent circuit for the LTC2228/LTC2227/LTC2226 CMOS differential sample-and-hold. The analog inputs are connected to the sampling capacitors (C_{SAMPLE}) through NMOS transistors. The capacitors shown attached to each input ($C_{\text{PARASITIC}}$) are the summation of all other capacitance associated with each input.

During the sample phase when CLK is low, the transistors connect the analog inputs to the sampling capacitors and they charge to and track the differential input voltage. When CLK transitions from low to high, the sampled input voltage is held on the sampling capacitors. During the hold phase when CLK is high, the sampling capacitors are disconnected from the input and the held voltage is passed to the ADC core for processing. As CLK transitions from high to low, the inputs are reconnected to the sampling capacitors to acquire a new sample. Since the sampling capacitors still hold the previous sample, a charging glitch proportional to the change in voltage between samples will be seen at this time. If the change between the last sample and the new sample is small, the charging glitch seen at the input will be small. If the input change is large, such as the change seen with input frequencies near Nyquist, then a larger charging glitch will be seen.

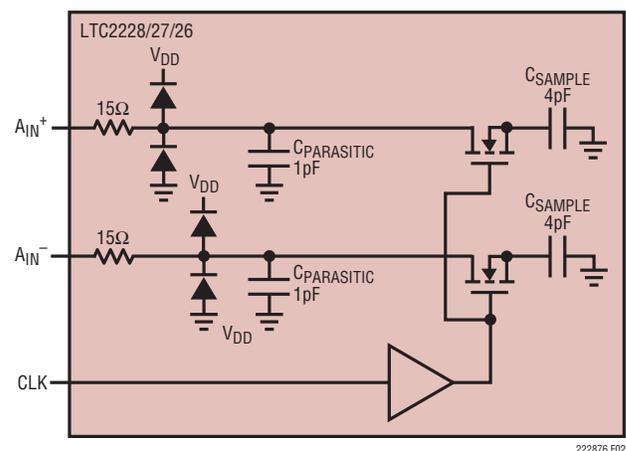


Figure 2. Equivalent Input Circuit

APPLICATIONS INFORMATION

Single-Ended Input

For cost-sensitive applications, the analog inputs can be driven single ended. With a single-ended input the harmonic distortion and INL will degrade, but the SNR and DNL will remain unchanged. For a single-ended input, A_{IN}^+ should be driven with the input signal and A_{IN}^- should be connected to 1.5V or V_{CM} .

Common Mode Bias

For optimal performance the analog inputs should be driven differentially. Each input should swing $\pm 0.5V$ for the 2V range or $\pm 0.25V$ for the 1V range, around a common mode voltage of 1.5V. The V_{CM} output pin (Pin 31) may be used to provide the common mode bias level. V_{CM} can be tied directly to the center tap of a transformer to set the DC input level or as a reference level to an op amp differential driver circuit. The V_{CM} pin must be bypassed to ground close to the ADC with a 2.2 μF or greater capacitor.

Input Drive Impedance

As with all high performance, high speed ADCs, the dynamic performance of the LTC2228/LTC2227/LTC2226 can be influenced by the input drive circuitry, particularly the second and third harmonics. Source impedance and input reactance can influence SFDR. At the falling edge of CLK, the sample-and-hold circuit will connect the 4pF sampling capacitor to the input pin and start the sampling period. The sampling period ends when CLK rises, holding the sampled input on the sampling capacitor. Ideally the input circuitry should be fast enough to fully charge the sampling capacitor during the sampling period $1/(2F_{ENCODE})$;

however, this is not always possible and the incomplete settling may degrade the SFDR. The sampling glitch has been designed to be as linear as possible to minimize the effects of incomplete settling.

For the best performance, it is recommended to have a source impedance of 100 Ω or less for each input. The source impedance should be matched for the differential inputs. Poor matching will result in higher even order harmonics, especially the second.

Input Drive Circuits

Figure 3 shows the LTC2228/LTC2227/LTC2226 being driven by an RF transformer with a center tapped secondary. The secondary center tap is DC biased with V_{CM} , setting the ADC input signal at its optimum DC level. Terminating on the transformer secondary is desirable, as this provides a common mode path for charging glitches caused by the sample and hold. Figure 3 shows a 1:1 turns ratio transformer. Other turns ratios can be used if the source impedance seen by the ADC does not exceed 100 Ω for each ADC input. A disadvantage of using a transformer is the loss of low frequency response. Most small RF transformers have poor performance at frequencies below 1MHz.

Figure 4 demonstrates the use of a differential amplifier to convert a single-ended input signal into a differential input signal. The advantage of this method is that it provides low frequency input response; however, the limited gain bandwidth of most op amps will limit the SFDR at high input frequencies.

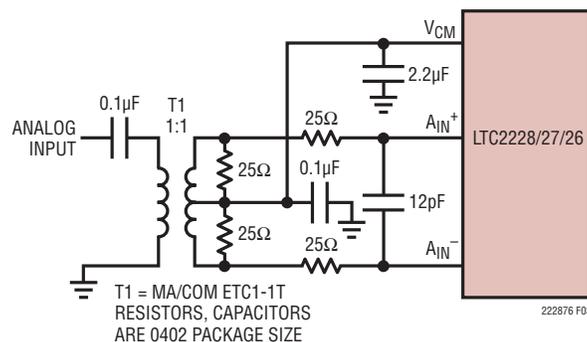


Figure 3. Single-Ended to Differential Conversion Using a Transformer

APPLICATIONS INFORMATION

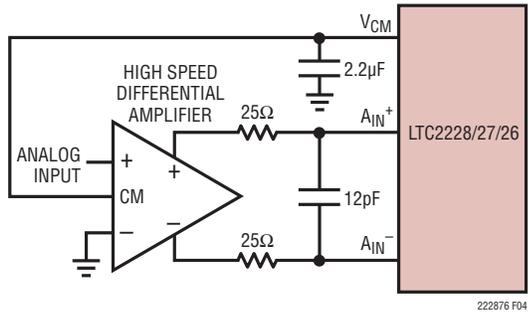


Figure 4. Differential Drive with an Amplifier

Figure 5 shows a single-ended input circuit. The impedance seen by the analog inputs should be matched. This circuit is not recommended if low distortion is required.

The 25Ω resistors and 12pF capacitor on the analog inputs serve two purposes: isolating the drive circuitry from the sample-and-hold charging glitches and limiting the wideband noise at the converter input.

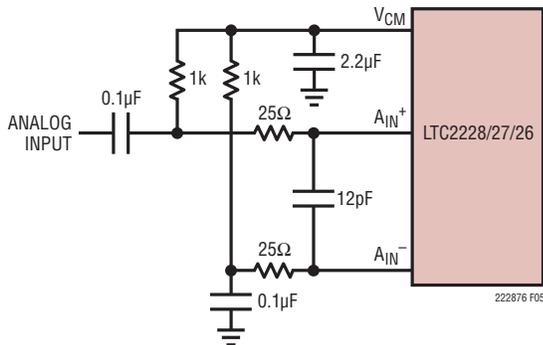


Figure 5. Single-Ended Drive

For input frequencies above 70MHz, the input circuits of Figure 6, 7 and 8 are recommended. The balun transformer gives better high frequency response than a flux coupled center tapped transformer. The coupling capacitors allow the analog inputs to be DC biased at 1.5V. In Figure 8, the series inductors are impedance matching elements that maximize the ADC bandwidth.

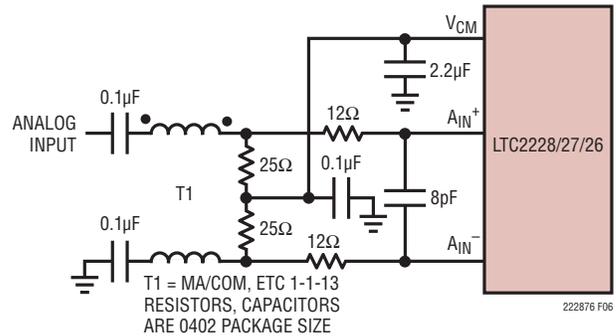


Figure 6. Recommended Front-End Circuit for Input Frequencies Between 70MHz and 170MHz

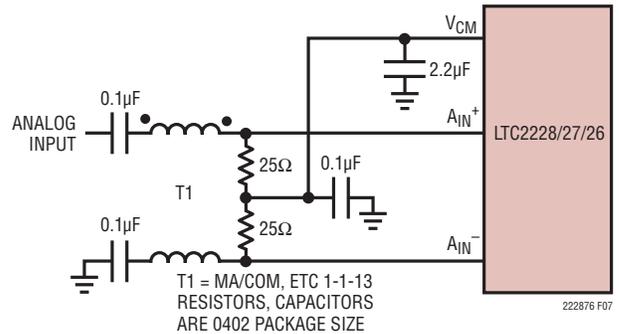


Figure 7. Recommended Front-End Circuit for Input Frequencies Between 170MHz and 300MHz

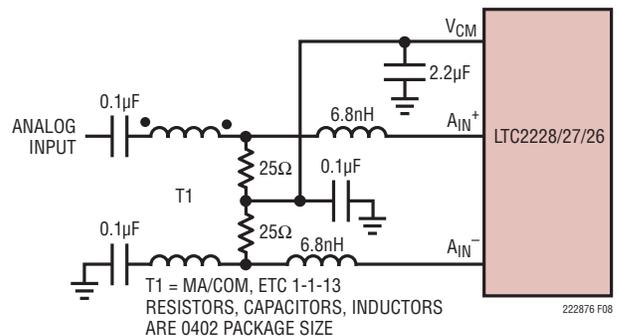


Figure 8. Recommended Front-End Circuit for Input Frequencies Above 300MHz

TYPICAL APPLICATIONS

Reference Operation

Figure 9 shows the LTC2228/LTC2227/LTC2226 reference circuitry consisting of a 1.5V bandgap reference, a difference amplifier and switching and control circuit. The internal voltage reference can be configured for two pin selectable input ranges of 2V ($\pm 1V$ differential) or 1V ($\pm 0.5V$ differential). Tying the SENSE pin to V_{DD} selects the 2V range; tying the SENSE pin to V_{CM} selects the 1V range.

The 1.5V bandgap reference serves two functions: its output provides a DC bias point for setting the common mode voltage of any external input circuitry; additionally, the reference is used with a difference amplifier to generate the differential reference levels needed by the internal ADC circuitry. An external bypass capacitor is required for the 1.5V reference output, V_{CM} . This provides a high frequency low impedance path to ground for internal and external circuitry.

The difference amplifier generates the high and low reference for the ADC. High speed switching circuits are connected to these outputs and they must be externally bypassed. Each output has two pins. The multiple output pins are needed to reduce package inductance. Bypass capacitors must be connected as shown in Figure 9.

Other voltage ranges in-between the pin selectable ranges can be programmed with two external resistors as shown in Figure 10. An external reference can be used by applying its output directly or through a resistor divider to SENSE. It is not recommended to drive the SENSE pin with a logic device. The SENSE pin should be tied to the appropriate level as close to the converter as possible. If the SENSE pin is driven externally, it should be bypassed to ground as close to the device as possible with a $1\mu F$ ceramic capacitor.

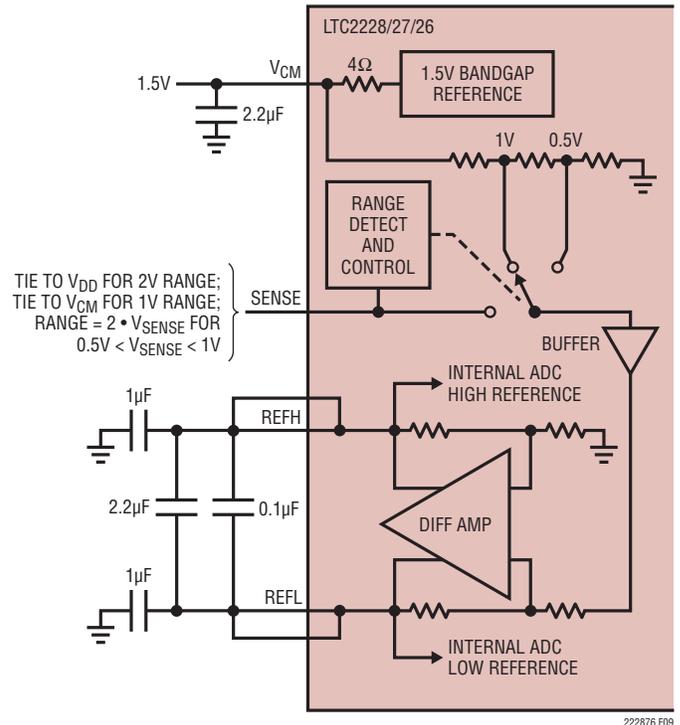


Figure 9. Equivalent Reference Circuit

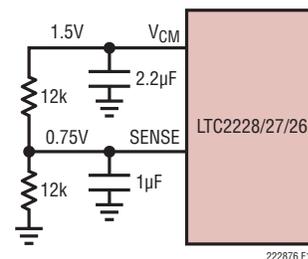


Figure 10. 1.5V Range ADC

APPLICATIONS INFORMATION

Input Range

The input range can be set based on the application. The 2V input range will provide the best signal-to-noise performance while maintaining excellent SFDR. The 1V input range will have better SFDR performance, but the SNR will degrade by 3.8dB. See the Typical Performance Characteristics section.

Driving the Clock Input

The CLK input can be driven directly with a CMOS or TTL level signal. A sinusoidal clock can also be used along with a low jitter squaring circuit before the CLK pin (Figure 11).

The noise performance of the LTC2228/LTC2227/LTC2226 can depend on the clock signal quality as much as on the analog input. Any noise present on the clock signal will result in additional aperture jitter that will be RMS summed with the inherent ADC aperture jitter.

In applications where jitter is critical, such as when digitizing high input frequencies, use as large an amplitude as possible. Also, if the ADC is clocked with a sinusoidal signal, filter the CLK signal to reduce wideband noise and distortion products generated by the source.

Figures 12 and 13 show alternatives for converting a differential clock to the single-ended CLK input. The use of a transformer provides no incremental contribution to phase noise. The LVDS or PECL to CMOS translators provide little degradation below 70MHz, but at 140MHz will degrade the SNR compared to the transformer solution.

The nature of the received signals also has a large bearing on how much SNR degradation will be experienced. For high crest factor signals such as WCDMA or OFDM, where the nominal power level must be at least 6dB to 8dB below full scale, the use of these translators will have a lesser impact.

The transformer in the example may be terminated with the appropriate termination for the signaling in use. The use of a transformer with a 1:4 impedance ratio may be desirable in cases where lower voltage differential signals are considered. The center tap may be bypassed to ground through a capacitor close to the ADC if the differential signals originate on a different plane. The use of a capacitor at the input may result in peaking, and depending on transmission line length may require a 10Ω to 20Ω series resistor to act as both a lowpass filter for high frequency noise that may be induced into the clock line by neighboring digital signals, as well as a damping mechanism for reflections.

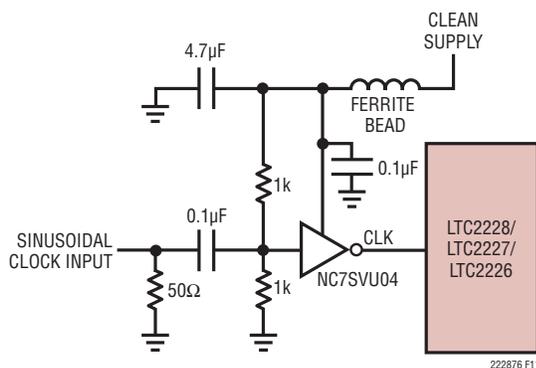
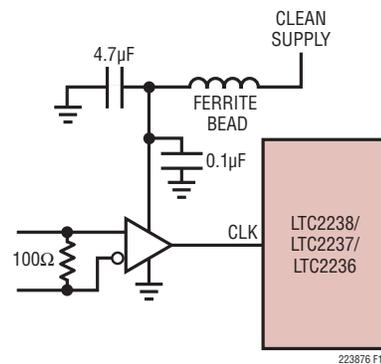


Figure 11. Single-Ended CLK Drive



IF LVDS USE FIN1002 OR FIN1018.
FOR PECL, USE AZ1000ELT21 OR SIMILAR

Figure 12. CLK Drive Using an LVDS or PECL-to-CMOS Converter

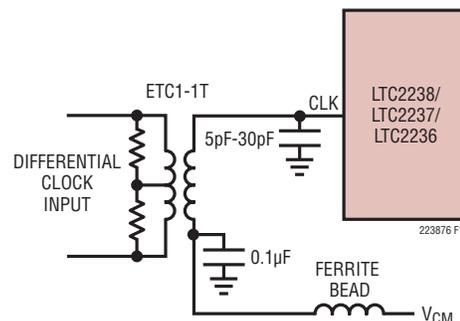


Figure 13. LVDS or PECL CLK Drive Using a Transformer

APPLICATIONS INFORMATION

digital outputs of the LTC2228/LTC2227/LTC2226 should drive a minimal capacitive load to avoid possible interaction between the digital outputs and sensitive input circuitry. The output should be buffered with a device such as an ALVCH16373 CMOS latch. For full speed operation the capacitive load should be kept under 10pF.

Lower OV_{DD} voltages will also help reduce interference from the digital outputs.

Data Format

Using the MODE pin, the LTC2228/LTC2227/LTC2226 parallel digital output can be selected for offset binary or 2's complement format. Connecting MODE to GND or $1/3V_{DD}$ selects offset binary output format. Connecting MODE to $2/3V_{DD}$ or V_{DD} selects 2's complement output format. An external resistor divider can be used to set the $1/3V_{DD}$ or $2/3V_{DD}$ logic values. Table 2 shows the logic states for the MODE pin.

Table 2. MODE Pin Function

MODE PIN	OUTPUT FORMAT	CLOCK DUTY CYCLE STABILIZER
0	Offset Binary	Off
$1/3V_{DD}$	Offset Binary	On
$2/3V_{DD}$	2's Complement	On
V_{DD}	2's Complement	Off

Overflow Bit

When OF outputs a logic high the converter is either over-ranged or underranged.

Output Driver Power

Separate output power and ground pins allow the output drivers to be isolated from the analog circuitry. The power supply for the digital output buffers, OV_{DD} , should be tied to the same power supply as for the logic being driven. For example if the converter is driving a DSP powered by a 1.8V supply, then OV_{DD} should be tied to that same 1.8V supply.

OV_{DD} can be powered with any voltage from 500mV up to 3.6V. OGND can be powered with any voltage from GND up to 1V and must be less than OV_{DD} . The logic outputs will swing between OGND and OV_{DD} .

Output Enable

The outputs may be disabled with the output enable pin, \overline{OE} . \overline{OE} high disables all data outputs including OF. The data access and bus relinquish times are too slow to allow the outputs to be enabled and disabled during full speed operation. The output Hi-Z state is intended for use during long periods of inactivity.

Sleep and Nap Modes

The converter may be placed in shutdown or nap modes to conserve power. Connecting SHDN to GND results in normal operation. Connecting SHDN to V_{DD} and \overline{OE} to V_{DD} results in sleep mode, which powers down all circuitry including the reference and typically dissipates 1mW. When exiting sleep mode it will take milliseconds for the output data to become valid because the reference capacitors have to recharge and stabilize. Connecting SHDN to V_{DD} and \overline{OE} to GND results in nap mode, which typically dissipates 15mW. In nap mode, the on-chip reference circuit is kept on, so that recovery from nap mode is faster than that from sleep mode, typically taking 100 clock cycles. In both sleep and nap modes, all digital outputs are disabled and enter the Hi-Z state.

Grounding and Bypassing

The LTC2228/LTC2227/LTC2226 require a printed circuit board with a clean, unbroken ground plane. A multilayer board with an internal ground plane is recommended. Layout for the printed circuit board should ensure that digital and analog signal lines are separated as much as possible. In particular, care should be taken not to run any digital track alongside an analog signal track or underneath the ADC.

High quality ceramic bypass capacitors should be used at the V_{DD} , OV_{DD} , V_{CM} , REFH, and REFL pins. Bypass capacitors must be located as close to the pins as possible. Of particular importance is the 0.1 μ F capacitor between REFH and REFL. This capacitor should be placed as close to the device as possible (1.5mm or less). A size 0402 ceramic capacitor is recommended. The large 2.2 μ F capacitor between REFH and REFL can be somewhat further away. The traces connecting the pins and bypass capacitors must be kept short and should be made as wide as possible.

TYPICAL APPLICATIONS

The LTC2228/LTC2227/LTC2226 differential inputs should run parallel and close to each other. The input traces should be as short as possible to minimize capacitance and to minimize noise pickup.

Heat Transfer

Most of the heat generated by the LTC2228/LTC2227/LTC2226 is transferred from the die through the bottom-side Exposed Pad and package leads onto the printed circuit board. For good electrical and thermal performance, the exposed pad should be soldered to a large grounded pad on the PC board. It is critical that all ground pins are connected to a ground plane of sufficient area.

Clock Sources for Undersampling

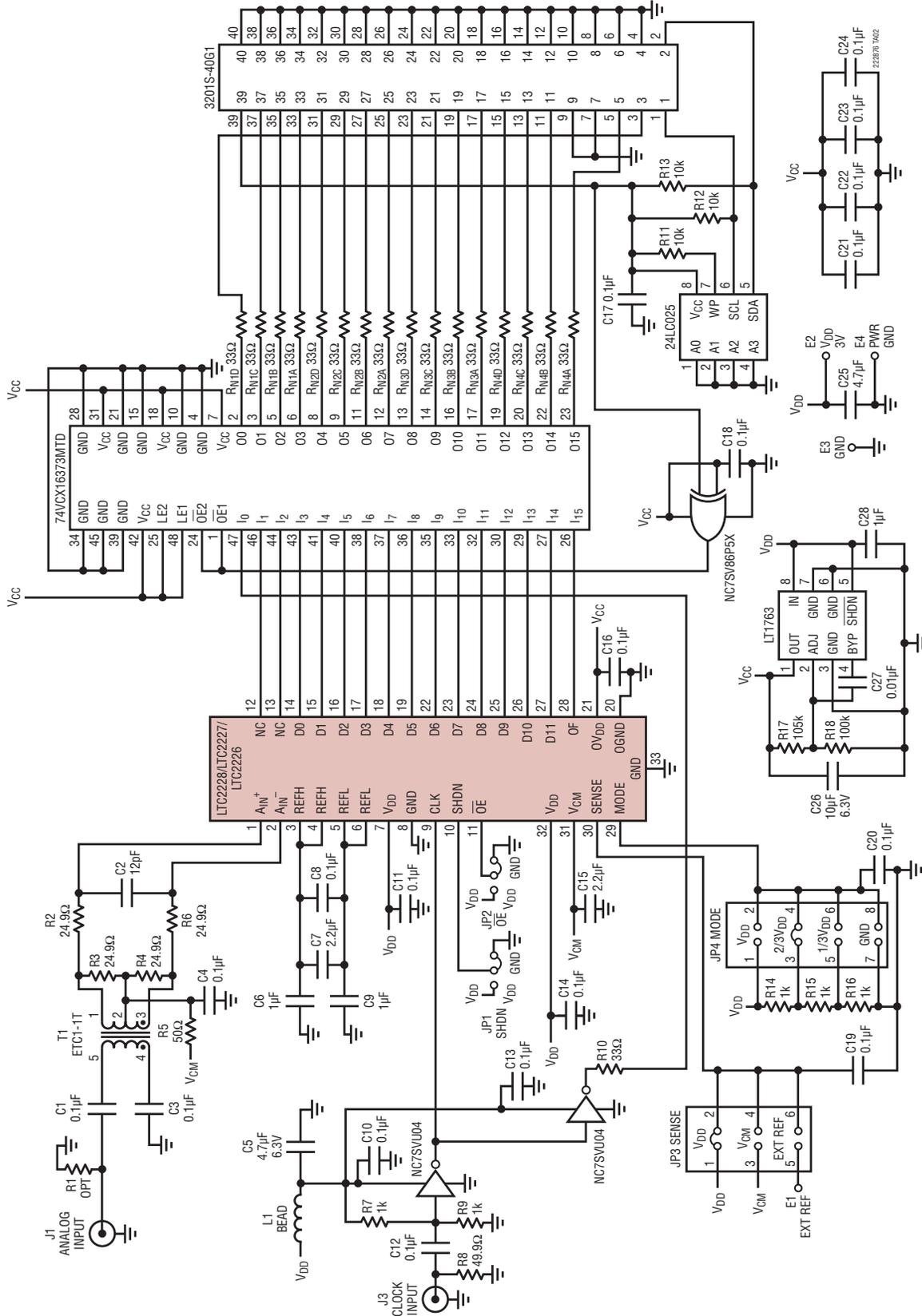
Undersampling raises the bar on the clock source and the higher the input frequency, the greater the sensitivity to clock jitter or phase noise. A clock source that degrades SNR of a full-scale signal by 1dB at 70MHz will degrade SNR by 3dB at 140MHz, and 4.5dB at 190MHz.

In cases where absolute clock frequency accuracy is relatively unimportant and only a single ADC is required, a 3V canned oscillator from vendors such as Saronix or Vectron can be placed close to the ADC and simply connected directly to the ADC. If there is any distance to the ADC, some source termination to reduce ringing that may occur even over a fraction of an inch is advisable. You must not allow the clock to overshoot the supplies or performance will suffer. Do not filter the clock signal with a narrow band filter unless you have a sinusoidal clock source, as the rise and fall time artifacts present in typical digital clock signals will be translated into phase noise.

The lowest phase noise oscillators have single-ended sinusoidal outputs, and for these devices the use of a filter close to the ADC may be beneficial. This filter should be close to the ADC to both reduce roundtrip reflection times, as well as reduce the susceptibility of the traces between the filter and the ADC. If you are sensitive to close-in phase noise, the power supply for oscillators and any buffers must be very stable, or propagation delay variation with supply will translate into phase noise. Even though these clock sources may be regarded as digital devices, do not operate them on a digital supply. If your clock is also used to drive digital devices such as an FPGA, you should locate the oscillator, and any clock fan-out devices close to the ADC, and give the routing to the ADC precedence. The clock signals to the FPGA should have series termination at the source to prevent high frequency noise from the FPGA disturbing the substrate of the clock fan-out device. If you use an FPGA as a programmable divider, you must re-time the signal using the original oscillator, and the re-timing flip-flop as well as the oscillator should be close to the ADC, and powered with a very quiet supply.

For cases where there are multiple ADCs, or where the clock source originates some distance away, differential clock distribution is advisable. This is advisable both from the perspective of EMI, but also to avoid receiving noise from digital sources both radiated, as well as propagated in the waveguides that exist between the layers of multilayer PCBs. The differential pairs must be close together, and distanced from other signals. The differential pair should be guarded on both sides with copper distanced at least 3x the distance between the traces, and grounded with vias no more than 1/4 inch apart.

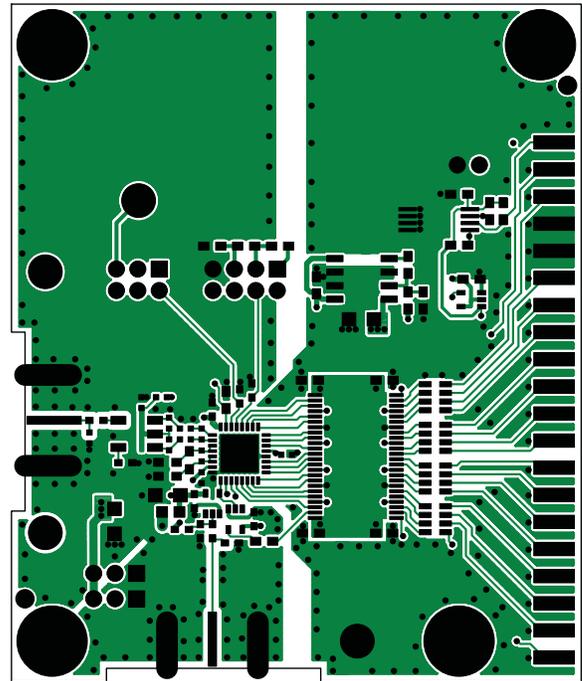
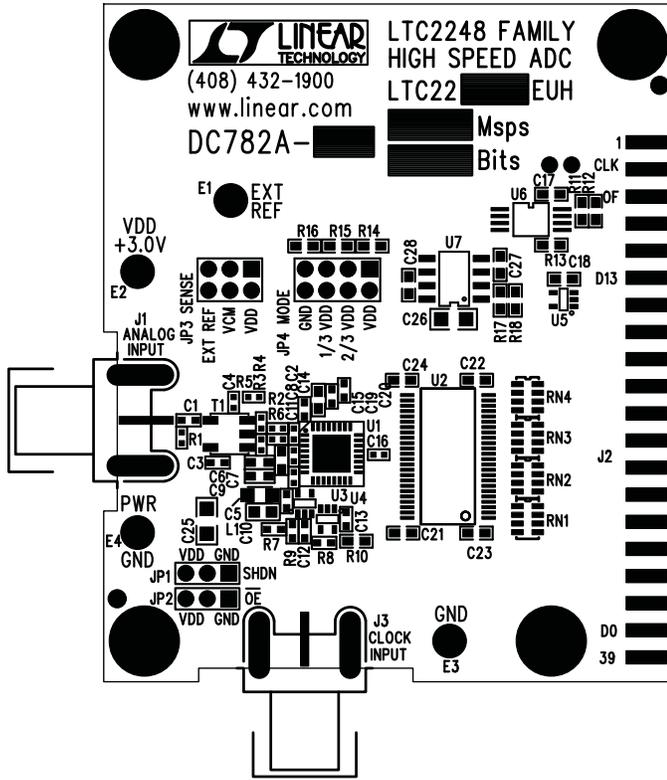
APPLICATIONS INFORMATION



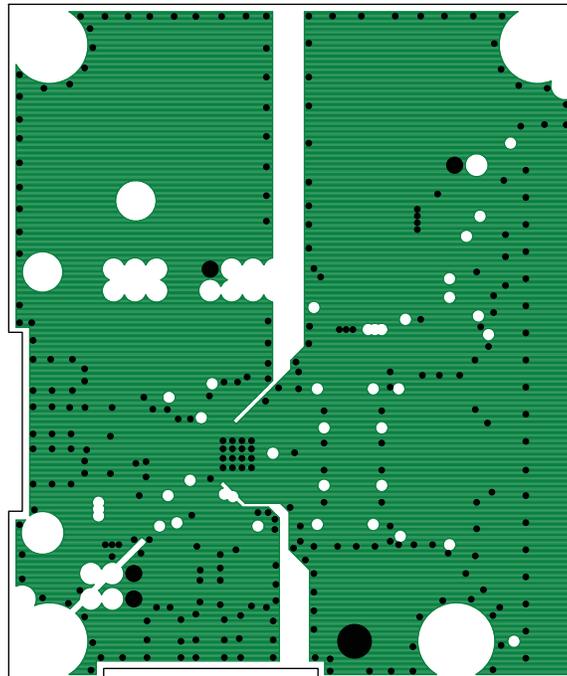
APPLICATIONS INFORMATION

Silkscreen Top

Topside

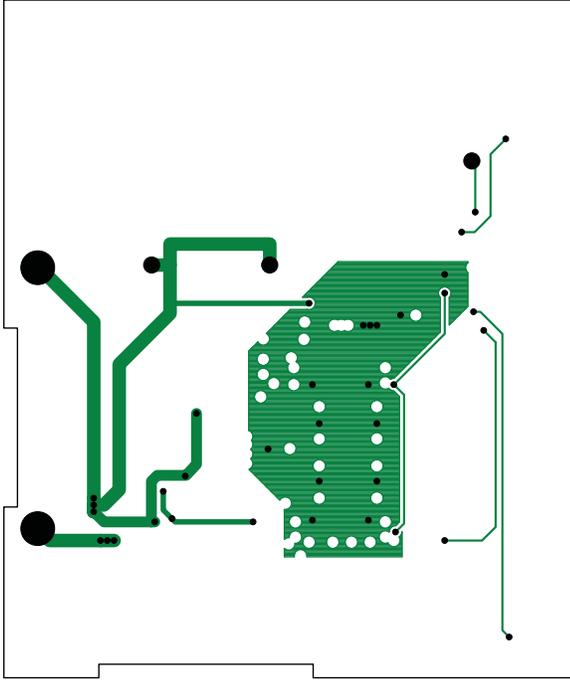


Inner Layer 2 GND

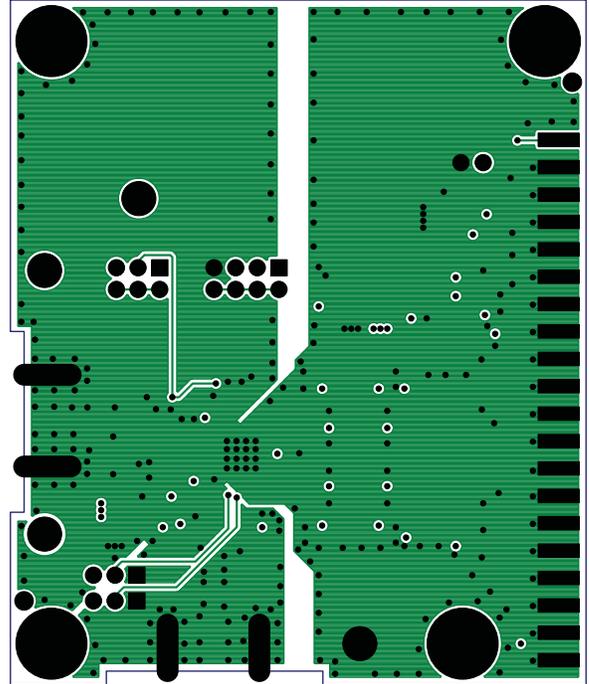


APPLICATIONS INFORMATION

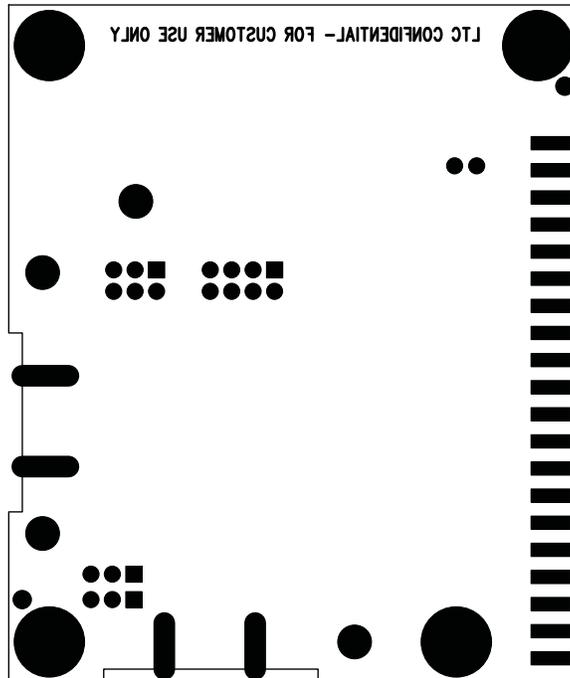
Inner Layer 3 Power



Bottomside



Silkscreen Bottom



LTC2228/LTC2227/LTC2226

RELATED PARTS

PART NUMBER	DESCRIPTION	COMMENTS
LTC1748	14-Bit, 80Msps, 5V ADC	76.3dB SNR, 90dB SFDR, 48-Pin TSSOP Package
LTC1750	14-Bit, 80Msps, 5V Wideband ADC	Up to 500MHz IF Undersampling, 90dB SFDR
LT1993-2	High Speed Differential Op Amp	800MHz BW, 70dBc Distortion at 70MHz, 6dB Gain
LT1994	Low Noise, Low Distortion Fully Differential Input/Output Amplifier/Driver	Low Distortion: -94dBc at 1MHz
LTC2202	16-Bit, 10Msps, 3V ADC, Lowest Power	150mW, 81.6dB SNR, 100dB SFDR, 48-Pin QFN
LTC2208	16-Bit, 130Msps, 3V ADC, LVDS Outputs	1250mW, 78dB SNR, 100dB SFDR, 64-Pin QFN
LTC2220-1	12-Bit, 185Msps, 3V ADC, LVDS Outputs	910mW, 67.7dB SNR, 80dB SFDR, 64-Pin QFN
LTC2224	12-Bit, 135Msps, 3V ADC, High IF Sampling	630mW, 67.6dB SNR, 84dB SFDR, 48-Pin QFN
LTC2225	12-Bit, 10Msps, 3V ADC, Lowest Power	60mW, 71.3dB SNR, 90dB SFDR, 32-Pin QFN
LTC2226	12-Bit, 25Msps, 3V ADC, Lowest Power	75mW, 71.4dB SNR, 90dB SFDR, 32-Pin QFN
LTC2227	12-Bit, 40Msps, 3V ADC, Lowest Power	120mW, 71.4dB SNR, 90dB SFDR, 32-Pin QFN
LTC2228	12-Bit, 65Msps, 3V ADC, Lowest Power	205mW, 71.3dB SNR, 90dB SFDR, 32-Pin QFN
LTC2229	12-Bit, 80Msps, 3V ADC, Lowest Power	211mW, 70.6dB SNR, 90dB SFDR, 32-Pin QFN
LTC2236	10-Bit, 25Msps, 3V ADC, Lowest Power	75mW, 61.8dB SNR, 85dB SFDR, 32-Pin QFN
LTC2237	10-Bit, 40Msps, 3V ADC, Lowest Power	120mW, 61.8dB SNR, 85dB SFDR, 32-Pin QFN
LTC2238	10-Bit, 65Msps, 3V ADC, Lowest Power	205mW, 61.8dB SNR, 85dB SFDR, 32-Pin QFN
LTC2239	10-Bit, 80Msps, 3V ADC, Lowest Power	211mW, 61.6dB SNR, 85dB SFDR, 32-Pin QFN
LTC2245	14-Bit, 10Msps, 3V ADC, Lowest Power	60mW, 74.4dB SNR, 90dB SFDR, 32-Pin QFN
LTC2246	14-Bit, 25Msps, 3V ADC, Lowest Power	75mW, 74.5dB SNR, 90dB SFDR, 32-Pin QFN
LTC2247	14-Bit, 40Msps, 3V ADC, Lowest Power	120mW, 74.4dB SNR, 90dB SFDR, 32-Pin QFN
LTC2248	14-Bit, 65Msps, 3V ADC, Lowest Power	205mW, 74.3dB SNR, 90dB SFDR, 32-Pin QFN
LTC2249	14-Bit, 80Msps, 3V ADC, Lowest Power	222mW, 73dB SNR, 90dB SFDR, 32-Pin QFN
LTC2250	10-Bit, 105Msps, 3V ADC, Lowest Power	320mW, 61.6dB SNR, 85dB SFDR, 32-Pin QFN
LTC2251	10-Bit, 125Msps, 3V ADC, Lowest Power	395mW, 61.6dB SNR, 85dB SFDR, 32-Pin QFN
LTC2252	12-Bit, 105Msps, 3V ADC, Lowest Power	320mW, 70.2dB SNR, 88dB SFDR, 32-Pin QFN
LTC2253	12-Bit, 125Msps, 3V ADC, Lowest Power	395mW, 70.2dB SNR, 88dB SFDR, 32-Pin QFN
LTC2254	14-Bit, 105Msps, 3V ADC, Lowest Power	320mW, 72.4dB SNR, 88dB SFDR, 32-Pin QFN
LTC2255	14-Bit, 125Msps, 3V ADC, Lowest Power	395mW, 72.5dB SNR, 88dB SFDR, 32-Pin QFN
LTC2284	14-Bit, Dual, 105Msps, 3V ADC, Low Crosstalk	540mW, 72.4dB SNR, 88dB SFDR, 64-Pin QFN
LT5512	DC-3GHz High Signal Level Downconverting Mixer	DC to 3GHz, 21dBm IIP3, Integrated LO Buffer
LT5514	Ultralow Distortion IF Amplifier/ADC Driver with Digitally Controlled Gain	450MHz to 1dB BW, 47dB OIP3, Digital Gain Control 10.5dB to 33dB in 1.5dB/Step
LT5515	1.5GHz to 2.5GHz Direct Conversion	High IIP3: 20dBm at 1.9GHz, Quadrature Demodulator Integrated LO Quadrature Generator
LT5516	800MHz to 1.5GHz Direct Conversion	High IIP3: 21.5dBm at 900MHz, Quadrature Demodulator Integrated LO Quadrature Generator
LT5517	40MHz to 900MHz Direct Conversion	High IIP3: 21dBm at 800MHz, Quadrature Demodulator Integrated LO Quadrature Generator
LT5522	600MHz to 2.7GHz High Linearity Downconverting Mixer	4.5V to 5.25V Supply, 25dBm IIP3 at 900MHz. NF = 12.5dB, 50W Single-Ended RF and LO Ports

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